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# **RF2484**

#### **DIRECT QUADRATURE MODULATOR**

RoHS Compliant & Pb-Free Product Package Style: QFN, 16-pin, 4x4

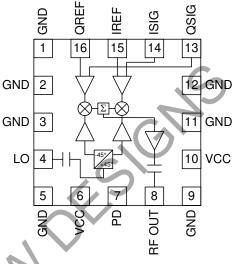


#### **Features**

- Typical Carrier Suppression > 35 dBc, Sideband Suppression > 35 dBc over temperature with highly linear operation
- Noise Floor better than -152dBm/Hz from 800MHz to 2200MHz
- Single 5V Power Supply

## **Applications**

- Dual-Band CDMA Base Stations
- TDMA/TDMA-EDGE Base Stations
- GSM-EDGE/EGSM Base Stations
- W-CDMA Base Stations
- WLAN and WLL Systems
- GMSK, QPSK, DQPSK, QAM Modulation



Functional Block Diagram

# **Product Description**

The RF2484 is a monolithic integrated quadrature modulator IC capable of universal direct modulation for high-frequency AM, PM, or compound carriers. This low-cost IC features excellent linearity, noise floor, and over-temperature carrier suppression performance. The device implements differential amplifiers for the modulation inputs, 90° carrier phase shift network, carrier limiting amplifiers, two matched double-balanced mixers, summing amplifier, and an output RF amplifier which will drive  $50\Omega$  from 800 MHz to 2500 MHz. It is packaged in a small industry-standard QFN 16-pin plastic package.

#### **Ordering Information**

RF2484 Direct Quadrature Modulator
RF2484PCBA-410 Fully Assembled Evaluation Board

## **Optimum Technology Matching® Applied**

# **RF2484**



#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Supply Voltage	-0.5 to +7.5	V <sub>DC</sub>
Input LO and RF Levels	+10	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



#### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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Parameter	Specification			Unit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
LO Input					T=25°C, V <sub>CC</sub> =5V, V <sub>REF</sub> =4.1V; I and Q driven single-ended	
Frequency Range	800		2500	MHz		
Power Level	-6		+6	dBm		
Input Impedance		45-j95		Ω	At 880MHz	
		52-j54		Ω	At 1960MHz	
		58-j50		Ω	At 2140 MHz	
		63-j40		Ω	At 2400MHz	
Modulation Input						
Frequency Range	DC		250	MHz		
Reference Voltage (V <sub>REF</sub> )		4.1	V/	V		
Input Resistance		30	7	kΩ		
Input Bias Current			40	μΑ		
RF Output (880MHz)					LO = -5dBm at 880MHz; Single sideband testing unless otherwise noted	
CDMA Output Channel Power		-12		dBm	For ACPR=-72dBc; I&Q Amplitude=1.1V <sub>PP</sub> (single-ended)	
CDMA ACPR	, X	-72		dBc	Channel Power=-12dBm; see Test Setup for detailed information	
Carrier Suppression	50			dBc	T=25°C; P <sub>OUT</sub> =-10 dBm; optimized I,Q DC off- sets	
Carrier Suppression over Temperature	35			dBc	Temperature cycled from -40 °C to +85 °C after optimization at T=25 °C; P <sub>OUT</sub> =-10dBm	
Sideband Suppression	50			dBc	T=25°C; P <sub>OUT</sub> =-10dBm; optimized I,Q amplitude and phase balance	
Sideband Suppression over Temperature	35			dBc	Temperature cycled from -40 °C to +85 °C after optimization at T=25 °C; P <sub>OUT</sub> =-10dBm	
Broadband Noise Floor		-152.5		dBm/Hz	At 20 MHz offset, 30 kHz res BW, V <sub>CC</sub> =5V; ISIG, QSIG, IREF, and QREF tied to V <sub>REF</sub>	
EVM		2.3		%	See Test Setup for detailed information	
Phase Error		1		° RMS	See Test Setup for detailed information	
Rho		.9993			See Test Setup for detailed information	
Output Impedance		28-j72		Ω		



D	Specification			1114	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
RF Output (1960MHz)					LO=-5dBm at 1960MHz; Single sideband testing unless otherwise noted	
PCS CDMA Output Power		-13		dBm	For ACPR=-72dBc; I&Q Amplitude=1.2V <sub>PP</sub> (single-ended)	
PCS CDMA ACPR		-72		dBc	Channel Power=-13dBm; see Test Setup for detailed information	
Carrier Suppression	50			dBc	T=25°C; P <sub>OUT</sub> =-13dBm; optimized I,Q DC off- sets	
Carrier Suppression over Temperature	35			dBc	Temperature cycled from -40 °C to +85 °C after optimization at T=25 °C; P <sub>OUT</sub> =-13dBm	
Sideband Suppression	50			dBc	T=25°C; P <sub>OUT</sub> =-13dBm; optimized I,Q amplitude and phase balance	
Sideband Suppression over Temperature	35			dBc	Temperature cycled from -40 °C to +85 °C after optimization at T=25 °C; POUT=-13dBm	
Broadband Noise Floor		-154.5		dBm/Hz	At 20 MHz offset, 30 kHz res BW, $V_{\rm CC}$ =5V; ISIG, QSIG, IREF, and QREF tied to $V_{\rm REF}$	
EVM		2.3		%	See Test Setup for detailed information	
Phase Error		1		° RMS	See Test Setup for detailed information	
Rho		.9988			See Test Setup for detailed information	
Output Impedance		46-j22		Ω		
RF Output (2140MHz)					LO = -5 dBm at 2140 MHz; Single sideband testing unless otherwise noted	
W-CDMA Output Channel Power		-16		dBm	For ACPR=-60dBc; I&Q Amplitude=1.4V <sub>PP</sub> (single-ended)	
W-CDMA ACPR		-60		dBc	Channel Power=-16dBm; see Test Setup for detailed information	
Carrier Suppression	50	2		dBc	T=25°C; P <sub>OUT</sub> =-13dBm; optimized I,Q DC off- sets	
Carrier Suppression over Temperature	35			dBc	Temperature cycled from -40 °C to +85 °C after optimization at T=25 °C; P <sub>OUT</sub> =-13dBm	
Sideband Suppression	50			dBc	T=25°C; P <sub>OUT</sub> =-13dBm; optimized I,Q amplitude and phase balance	
Sideband Suppression over Temperature	35			dBc	Temperature cycled from -40 °C to +85 °C after optimization at T=25 °C; P <sub>OUT</sub> =-13dBm	
Broadband Noise Floor		-152		dBm/Hz	At 20MHz offset, 30kHz res BW, $V_{CC}$ =5V; ISIG, QSIG, IREF, and QREF tied to $V_{REF}$	
EVM		5.9		%	See Test Setup for detailed information	
Phase Error		2.4		° RMS	See Test Setup for detailed information	
Rho		.9961			See Test Setup for detailed information	
Output Impedance		58-j16		Ω		
Power Down						
Turn On/Off Time			100	ns		
PD Input Resistance	50			kΩ		
Power Control "ON"			2.8	V	Threshold voltage	
Power Control "OFF"	1.0	1.2		V	Threshold voltage	



Parameter	Specification			Unit	Condition	
Farameter	Min.	Тур.	o. Max.		Condition	
Power Supply						
Voltage		5.0		V	Specifications	
	4.5		6.0	V	Operating Limits	
Current		66	70	mA		
			25	μА	Power Down	



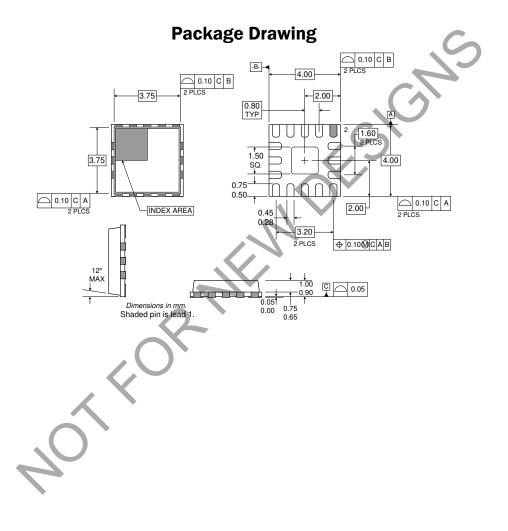


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Pin	Function	Description	Interface Schematic
1	GND	Ground connection. This pin should be connected directly to the ground plane.	
2	GND	Same as pin 1.	
3	GND	Same as pin 1.	
4	LO	The input of the phase shifting network. This pin has an internal DC blocking capacitor. This port is voltage-driven so matching at different frequencies is generally not required.	LD()W\ -
5	GND	Same as pin 1.	
6	VCC	Power supply. An external capacitor is needed if no other low frequency bypass capacitor is nearby.	
7	PD	Power Down control. When this pin is "low," all circuits are shut off. A "low" is typically 1.2V or less at room temperature. When this pin is "high" ( $V_{CC}$ ), all circuits are operating normally. If PD is below $V_{CC}$ , output power and performance will be degraded. Operating in this region is not recommended, although it might be useful in some applications where power control is required.	200 Ω V <sub>cc</sub>
8	RF OUT	RF Output. This pin has an internal DC blocking capacitor. At some frequencies, external matching may be needed to optimize output power. A small amount of DC current may be present at this output. As a result, if the voltage at this pin is measured using a high impedance probe, some DC voltage may be observed at this output.	
9	GND	Same as pin 1.	
10	VCC	Same as pin 6.	
11	GND	Same as pin 1.	
12	GND	Same as pin 1.	
13	Q SIG	Baseband input to the Q mixer. This pin is DC coupled. The input drive level determines output power and linearity performance; for better carrier suppression, sideband suppression, and dynamic range, the drive level should be as high as possible to meet the required linearity performance. The recommended DC level for this pin is 4.1V.  For optimum carrier suppression, the DC voltages on I REF, Q REF, I SIG and Q SIG should be adjusted slightly to compensate for inherent undesired internal DC offsets; for optimum sideband suppression, phase and signal amplitude on IREF, Q REF, I SIG and Q SIG should be adjusted slightly to compensate for inherent undesired internal offsets. See RFMD ANOOO1 for more detail.	100 Ω 1 p =
14	I SIG	Baseband input to the I mixer. This pin is DC coupled. The input drive level determines output power and linearity performance; for better carrier suppression, sideband suppression, and dynamic range, the drive level should be as high as possible to meet the required linearity performance. The recommended DC level for this pin is 4.1V; see pin 13 for more information.	100 Ω 1 p =
15	I REF	Reference voltage for the I mixer. This voltage should be the same as the DC voltage supplied to the I SIG pin. A voltage of 4.1V is recommended; see pin 13 for more information.  The SIG and REF inputs are inputs of a differential amplifier. Therefore the REF and SIG inputs are interchangeable. If swapping the I SIG and I REF pins, the Q SIG and Q REF also need to be swapped to maintain the correct phase. It is also possible to drive the SIG and REF inputs in a differential mode. This will increase the gain.	100 Ω 1 p =

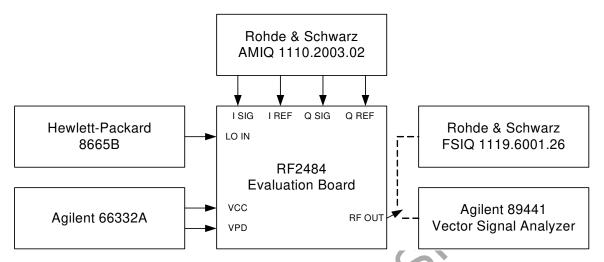


Pin	Function	Description	Interface Schematic
16	Q REF	Reference voltage for the Q mixer. This voltage should be the same as the DC voltage supplied to the Q SIG pin. A voltage of 4.1V is recommended; see pin 13 for more information.	100 Ω 1 p =
Pkg Base	GND	Ground connection. The package base should be connected to the ground plane.	





# **CDMA/W-CDMA Test Setup**



#### General

The above setup was used to evaluate the RF2484 under CDMA and W-CDMA modulation conditions. An AMIQ was required to provide the appropriate DC reference voltage (4.1V) for the I and Q pins, I and Q were driven single-endedly; differential drive may improve performance. A PC-controlled Rohde & Schwarz AMIQ generated the CDMA I and Q signals. In order to reduce AMIQ noise contributions to adjacent channel power, W-CDMA baseband signals were filtered using a high order low pass filter before application to the RF2484.

#### EVM, Phase Error, and Rho

To measure EVM, phase error, and Rho, signals were generated using the AMIQ and decoded with the Agilent VSA. For CDMA Cellular and PCS, I and Q input signals were generated with the Pilot Channel active, 32x oversampling and base station equifilters. For W-CDMA, the Common Pilot Channel was active with 8x oversampling and a root cosine filter. In all cases, relative signal amplitude levels were adjusted to optimize signal quality.

#### **CDMA Modulation Setup (Cellular and PCS)**

To measure ACPR, I and Q input signals were generated using the following settings:

- Pilot Channel active
- · Sync Channel active
- Paging Channel active
- 6 Traffic Channels active
- 32x Oversampling
- Base Station equifilter

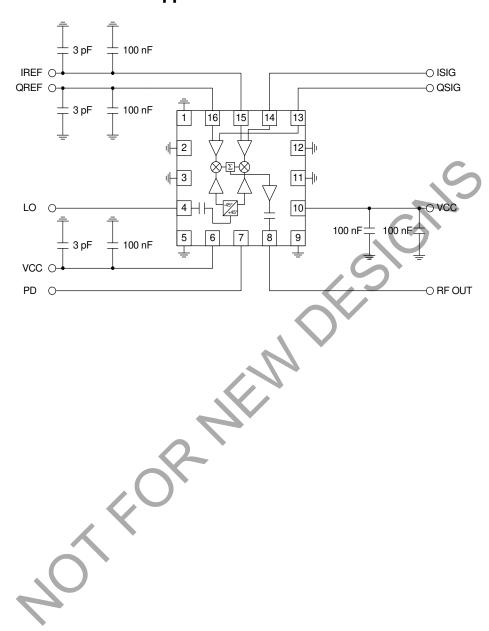
#### W-CDMA Modulation Setup

To measure W-CDMA ACPR, I and Q input signals were generated using the following settings in the AMIQ:

- · P-CPICH (Common Pilot Channel) active
- · P-SCH (Sync Channel) active
- P-CCPCH (Primary Common Control Physical Channel) active
- · P-ICH (Page Indicator Channel) Active
- DL-DPCCH (Dedicated Physical Control Channel) active
- 6 DPCH (Dedicated Physical Channels) active
- 8x Oversampling

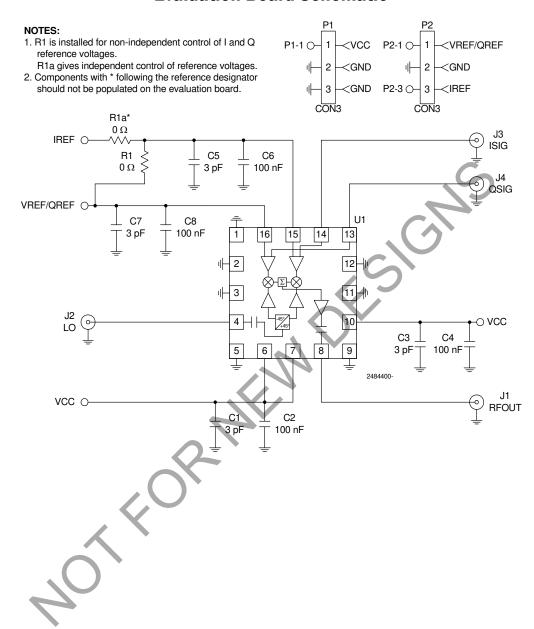


# **Application Schematic**





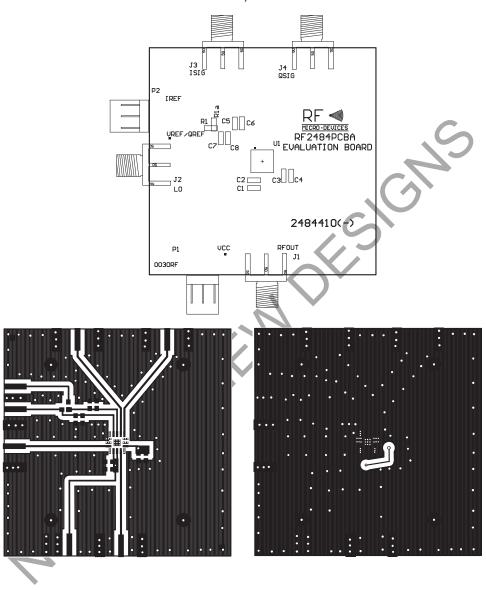
# **Evaluation Board Schematic**





# Evaluation Board Layout Board Size 2.0" x 2.0"

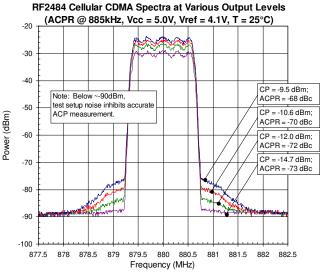
Board Thickness 0.028", Board Material FR-4

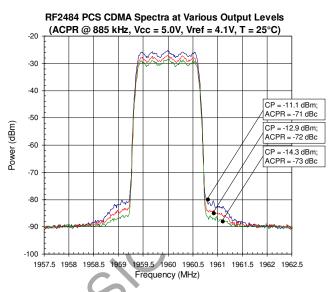


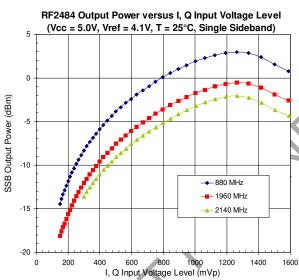


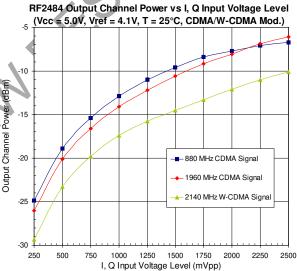


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## **RoHS\* Banned Material Content**

RoHS Compliant: Yes
Package total w eight in grams 0.037
Compliance Date Code: 526
Bill of Materials Revision: Pb Free Category: e3

Bill of Materials	Parts Per Million (PPM)							
	Pb	Cd	Hg	Cr VI	PBB	PBDE		
Die	0	0	0	0	0	0		
Molding Compound	0	0	0	0	0	0		
Lead Frame	0	0	0	0	0	0		
Die Attach Epoxy	0	0	0	0	0	0		
Wire	0	0	0	0	0	0		
Solder Plating	0	0	0	0	0	0		

This RoHS banned material content declaration was prepared solely on information, including analytical data, provided to RFMD by its suppliers, and applies to the Bill of Materials (BOM) revision noted above.

<sup>\*</sup> DIRECTIVE 2002/95/EC OF THE EUROPEAN PARLIAMENT AND OF THE COUNCIL of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment